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# August 2012

# FDP040N06 N-Channel PowerTrench<sup>®</sup> MOSFET 60V, 168A, 4.0mΩ

### Features

- $R_{DS(on)} = 3.2m\Omega$  (Typ.) @  $V_{GS} = 10V$ ,  $I_D = 75A$
- Fast Switching Speed
- Low Gate Charge
- High Performance Trench Technology for Extremely Low  $R_{\text{DS}(\text{on})}$
- High Power and Current Handling Capability
- RoHS Compliant

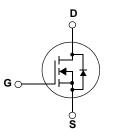
# **General Description**

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

# Application

• DC to DC convertors / Synchronous Rectification





#### MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol		Parameter		FDP040N06	Units	
V <sub>DSS</sub>	Drain to Source Voltage		60	V		
V <sub>GSS</sub>	Gate to Source Voltage			±20	V	
I <sub>D</sub>		-Continuous ( $T_c = 25^{\circ}C$ , Silicion Limited)		168*		
	Drain Current	-Continuous (T <sub>C</sub> = 100 <sup>o</sup> C, Silicion L	-Continuous (T <sub>C</sub> = 100 <sup>o</sup> C, Silicion Limited)		A	
		-Continuous (T <sub>C</sub> = 25 <sup>o</sup> C, Package L	imited)	120		
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	672	Α	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)			872	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	7.0	V/ns	
P <sub>D</sub>	David Disaination	$(T_{\rm C} = 25^{\rm o}{\rm C})$		231	W	
	Power Dissipation	- Derate above 25°C		1.54	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +175	°C	
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C	

\*Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 120A.

## **Thermal Characteristics**

Symbol	Parameter	FDP040N06	Units
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max	0.65	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max	62.5	0/00

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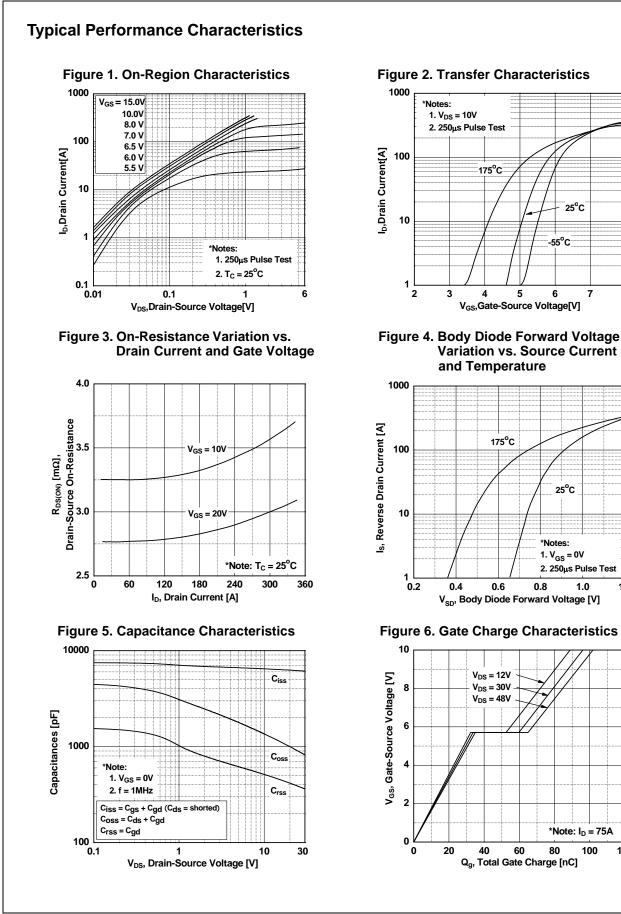
Device Ma	arking	Device	Packag	qe	Reel Size	Таре	e Width		Quantit	y
FDP040N06 FDP040N06		TO-220 Tube			-		50			
	l Char	antoriation -								
		acteristics ⊤ <sub>C</sub> = Parameter	25°C unless	otherwise			Min	Tim	Max	l Inite
Symbol Off Charad	torictio				Test Conditions		Min.	Тур.	Max.	Units
	-		ltogo	1 250		25 <sup>0</sup> C	60			V
BV <sub>DSS</sub> <u>ABV<sub>DSS</sub></u>		n to Source Breakdown Voltage kdown Voltage Temperature		$I_D = 250\mu A$ , $V_{GS} = 0V$ , $T_C = 25^{\circ}C$ $I_D = 250\mu A$ , Referenced to $25^{\circ}C$			60 -	- 0.04	-	V/°C
$\Delta T_{J}$	Coenici			V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V			-	-	1	
I <sub>DSS</sub>	Zero Ga	Zero Gate Voltage Drain Current		$V_{DS} = 60V, V_{GS} = 0V, T_C = 150^{\circ}C$			-	-	500	μA
I <sub>GSS</sub>	Gate to	Body Leakage Current	:		$20V, V_{DS} = 0V$		-	-	±100	nA
On Charac	teristic	S								
V <sub>GS(th)</sub>	Gate Th	Gate Threshold Voltage			V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250μA			3.5	4.5	V
R <sub>DS(on)</sub>		rain to Source On Resi	stance		0V, I <sub>D</sub> = 75A		-	3.2	4.0	mΩ
9FS	Forward	Forward Transconductance		$V_{DS} = 10V, I_{D} = 75A$			-	169	-	S
Dynamic C								6190	8235	~ 5
C <sub>iss</sub>				$V_{DS} = 25V, V_{GS} = 0V$			-	900	1195	pF pF
C <sub>oss</sub>		Capacitance Transfer Capacitance		f = 1MHz		-	385	580	pr pF	
C <sub>rss</sub>		ate Charge at 10V				-	102	133	nC	
Q <sub>g(tot)</sub> Q <sub>gs</sub>		to Drain "Miller" Charge		$V_{DS} = 48V, I_D = 75A$ $V_{GS} = 10V$ (Note 4)			_	32	-	nC
Q <sub>gd</sub>							_	32	-	nC
Switching										
-		Delay Time					_	30	70	ns
t <sub>d(on)</sub> t		Rise Time		$V_{DD} = 30V, I_D = 75A$ $V_{GS} = 10V, R_{GEN} = 4.7\Omega$		-	40	90	ns	
t <sub>r</sub>		f Delay Time				-	-	55	120	ns
t <sub>d(off)</sub>		Fall Time				(Note 4)	_	24	58	ns
t <sub>f</sub>			_			(11018 4)		24	50	113
		de Characteristics		o Forward	Current		-		100	•
l <sub>S</sub>	Maximum Continuous Drain to Source Dioo Maximum Pulsed Drain to Source Diode Fo						-	-	168 672	A
I <sub>SM</sub>		Source Diode Forward			V, I <sub>SD</sub> = 75A			-	1.3	A V
V <sub>SD</sub> t <sub>rr</sub>		Recovery Time	vollage				-	41	1.3	v ns
	I NEVEISE	INCOVERY TIME		$v_{GS} = 0$	V <sub>GS</sub> = 0V, I <sub>SD</sub> = 75A dI <sub>F</sub> /dt = 100A/μs		-	41		115

1: Repetitive Rating: Pulse width limited by maximum junction temperature 2: L = 0.31mH, I<sub>AS</sub> = 75A, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25\Omega, Starting T<sub>J</sub> = 25°C 3: I<sub>SD</sub> <75A, di/dt ≤ 200A/µs, V<sub>DD</sub> ≤ BV<sub>DSS</sub>, Starting T<sub>J</sub> = 25°C 4: Essentially Independent of Operating Temperature Typical Characteristics

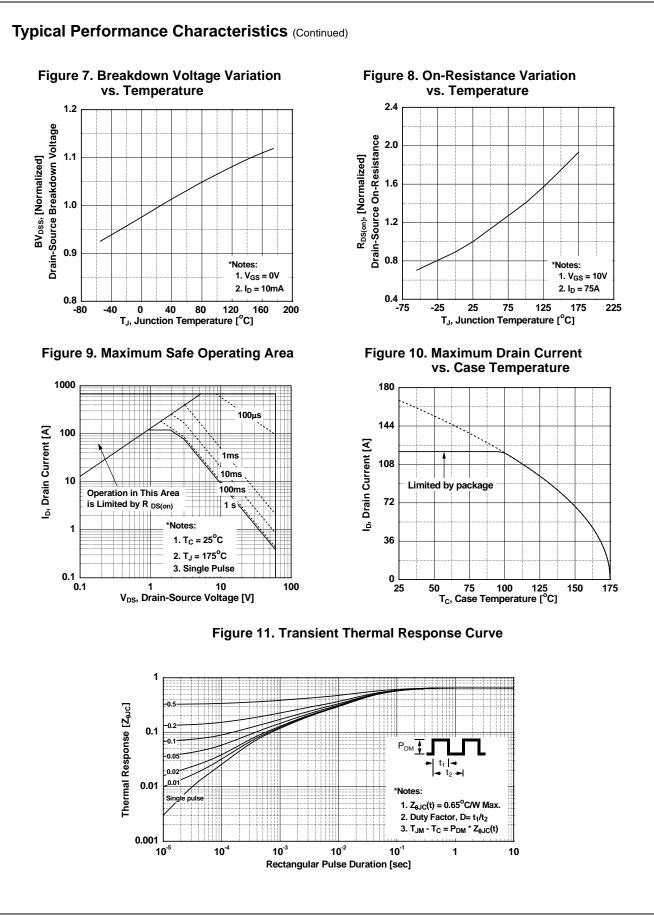


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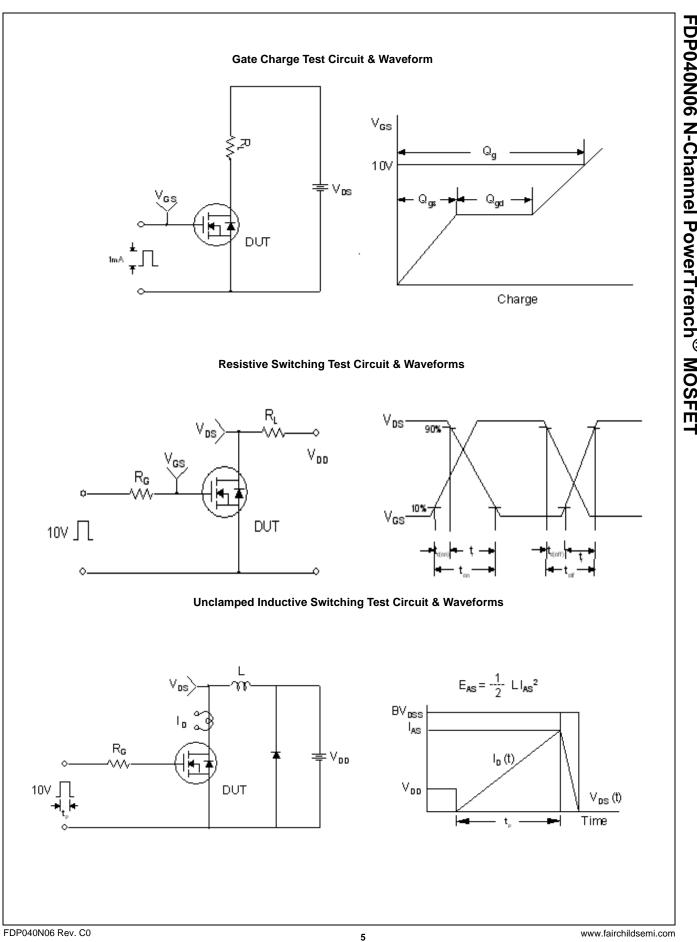


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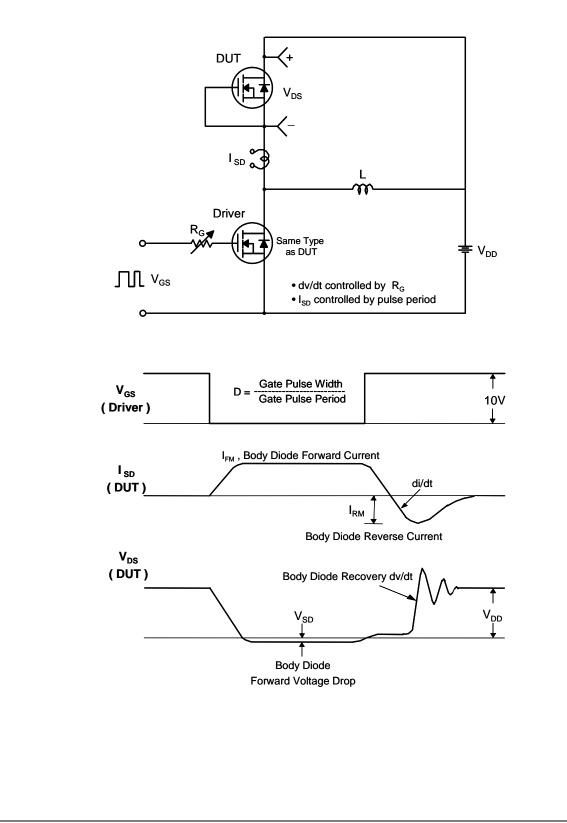


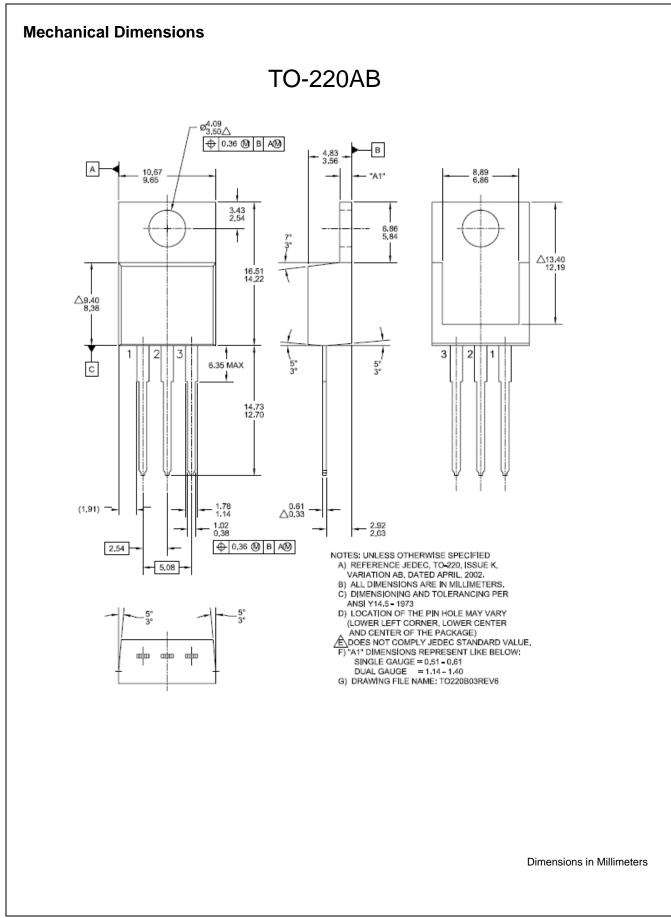
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Peak Diode Recovery dv/dt Test Circuit & Waveforms





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